

L Number	Hits	Search Text	DB	Time stamp
1	276	flux near2 pump	USPAT; US-PGPUB	2004/07/19 09:43
2	46	(flux near2 pump) and superconducting	USPAT; US-PGPUB	2004/07/19 09:01
3	11	("3568002"   "4688132"   "4906861"   "5110793"   "5181170"   "5225956"   "5347168"   "5376626"   "5612615"   "5623240"   "5680085").PN.	USPAT	2004/07/19 08:31
4	1	6157094.URPN.	USPAT	2004/07/19 08:32
5	2	5965959.URPN.	USPAT	2004/07/19 08:33
6	9	("3568002"   "4906861"   "5110793"   "5181170"   "5225956"   "5347168"   "5612615"   "5623240"   "5680085").PN.	USPAT	2004/07/19 08:33
7	1	"4599677".PN.	USPAT	2004/07/19 08:34
8	3	4973874.URPN.	USPAT	2004/07/19 08:35
9	1	"3356924".PN.	USPAT	2004/07/19 08:36
10	4	4709314.URPN.	USPAT	2004/07/19 08:36
11	3	3835369.URPN.	USPAT	2004/07/19 08:37
12	26	(flux near2 pump) and heat near2 sink	USPAT; US-PGPUB	2004/07/19 09:25
13	19	(flux near2 pump) and cryostat	USPAT; US-PGPUB	2004/07/19 09:43
14	412	flux near2 pump	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 09:43
15	24	(flux near2 pump) and cryostat	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 09:45
16	40	(flux near2 pump) and control\$3 near2 switches	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:01
17	11	(flux near2 pump) and temperature near2 (sensor detector)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:03
18	7	(flux near2 pump) and MOSFET	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:04
19	26	(flux near2 pump) and HEAT NEAR2 SINK	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:05
20	265	361/19.CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:06
21	7	(flux near2 pump) AND 361/19.CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:05
22	162	361/141.CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:23

24	982	(MOSFET TRANSISTOR SWITCH) NEAR3 COPPER	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:30
25	412	(flux near2 pump) AND (flux near2 pump)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:27
26	1	(flux near2 pump) AND ((MOSFET TRANSISTOR SWITCH) NEAR3 COPPER)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:27
27	12621	THERMAL NEAR2 CONDUCTING	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:29
28	80	(MOSFET TRANSISTOR SWITCH) NEAR3 (THERMAL NEAR2 CONDUCTING)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:29
29	104565	(MOSFET TRANSISTOR SWITCH) NEAR3 (ARRANG\$2 PLAC\$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:30
30	25202	COPPER NEAR2 PLATE	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:31
31	0	((MOSFET TRANSISTOR SWITCH) NEAR3 (ARRANG\$2 PLAC\$2)) NEAR4 (COPPER NEAR2 PLATE)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 11:02
32	13	((MOSFET TRANSISTOR SWITCH) NEAR3 (ARRANG\$2 PLAC\$2)) SAME (COPPER NEAR2 PLATE)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:31
33	1874	heat\$3 NEAR4 (COPPER NEAR2 PLATE)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 10:56
34	280	heat near2 sink NEAR4 (COPPER NEAR2 PLATE)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 11:03
35	166988	temperature near2 sensor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 11:04
36	1	(heat near2 sink NEAR4 (COPPER NEAR2 PLATE)) same (temperature near2 sensor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 11:09
37	12621	thermal near2 conducting	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/19 11:10

38	833	(thermal near2 conducting) same heat near2 sink	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 11:10
39	10	((thermal near2 conducting) same heat near2 sink) same sensor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 11:21
41	1370070	copper with thermal sensor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 11:22
45	298	(conducting near2 plate) same heat near2 sink	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 13:39
46	20	((conducting near2 plate) same heat near2 sink) and (thermal heat temperature) near2 (sensor detector)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 11:42
47	46976	parallel near2 (switch fet mosfet transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 12:25
49	148	heat near2 sink near3 platform	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 12:12
50	14413	conducting near2 plate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 12:12
51	284289	control\$3 near2 temperature	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 12:13
52	19	(conducting near2 plate) near3 (control\$3 near2 temperature)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 12:13
54	0	(MHz near2 (switch fet mosfet transistor)) and (flux near2 pump)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 13:34
55	910	361/139-143.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 13:34
56	11	(flux near2 pump) and 361/139-143.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/19 13:35